

BCR2AS-14A

700V - 2A - Triac

Low Power Use

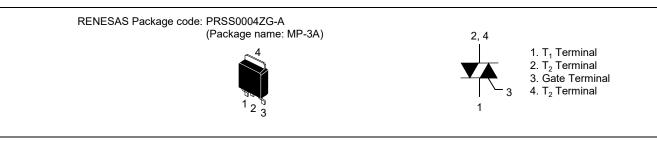
Data Sheet

R07DS0257EJ0101 Rev.1.01 May. 10, 2019

Features

- I_{T (RMS)} : 2 A
- V_{DRM} : 700 V
- I_{FGTI} , I_{RGTI} , $I_{RGT III}$: 10 mA

Outline



Tj: 125 °C

Planar Passivation Type

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Application

Small motor control, heater control, and other general purpose AC control applications.

Maximum Ratings

Parameter	Symbol	Voltage class	Unit
		14	
Repetitive peak off-state voltage ^{Note1}	V _{DRM}	700	V
Non-repetitive peak off-state voltage ^{Note1}	V _{DSM}	840	V

Notes: 1. Gate open.

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I _{T (RMS)}	2	A	Commercial frequency, sine full wave 360° conduction, Tc = 112° C ^{Note3}
Surge on-state current	Ітѕм	9	A	50 Hz sinewave 1 full cycle, peak value, non-repetitive
l ² t for fusing	l ² t	0.41	A²s	Value corresponding to 1 cycle of half wave 50 Hz, surge on-state current
Peak gate power dissipation	Рдм	1	W	
Average gate power dissipation	P _{G (AV)}	0.1	W	
Peak gate voltage	V _{GM}	6	V	
Peak gate current	I _{GM}	1	Α	
Junction Temperature	Tj	-40 to +125	°C	
Storage temperature	Tstg	-40 to +125	°C	



Electrical Characteristics

Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state current		IDRM	_	_	1.0	mA	Tj = 125°C, V _{DRM} applied
On-state voltage		V _{TM}	_	—	2.1	V	Tc = 25° C, I _{TM} = 3 A, instantaneous measurement
Gate trigger voltage ^{Note2}	Ι	VFGTI	_		2.0	V	Tj = 25°C, V _D = 6 V, R _L = 6 Ω, R _G = 330 Ω
	II	V _{RGTI}	_	_	2.0	V	
	III	Vrgtiii	_	_	2.0	V	
Gate trigger currentNote2	Ι	IFGTI			10	mA	$\label{eq:tilde} \begin{array}{l} Tj = 25^\circC, V_D = 6 \; V, R_L = 6 \; \Omega, \\ R_G = 330 \; \Omega \end{array}$
	II	IRGTI	_	_	10	mA	
	III	IRGTIII	_	—	10	mA	
Gate non-trigger voltage		V_{GD}	0.2			V	Tj = 125°C, V _D = 1/2 V _{DRM}
Thermal resistance		R _{th (j-c)}			4.0	°C/W	Junction to case ^{Note3}
Critical-rate of rise of off-state commutating voltage ^{Note4}		(dv/dt)c	0.5	—	—	V/µs	Tj = 125°C

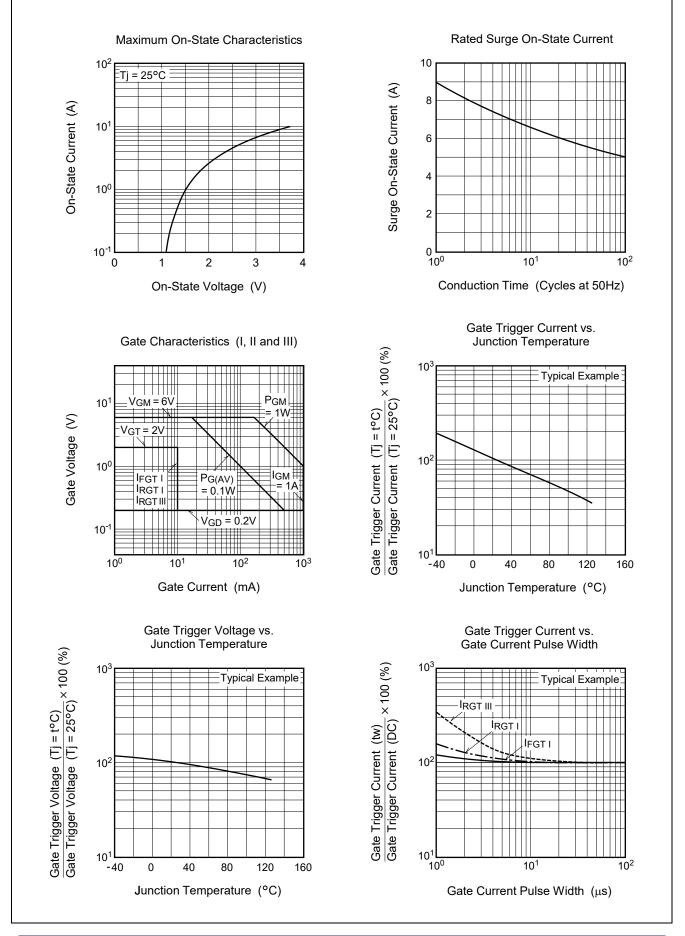
Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

3. Case temperature is measured on the T₂ tab.

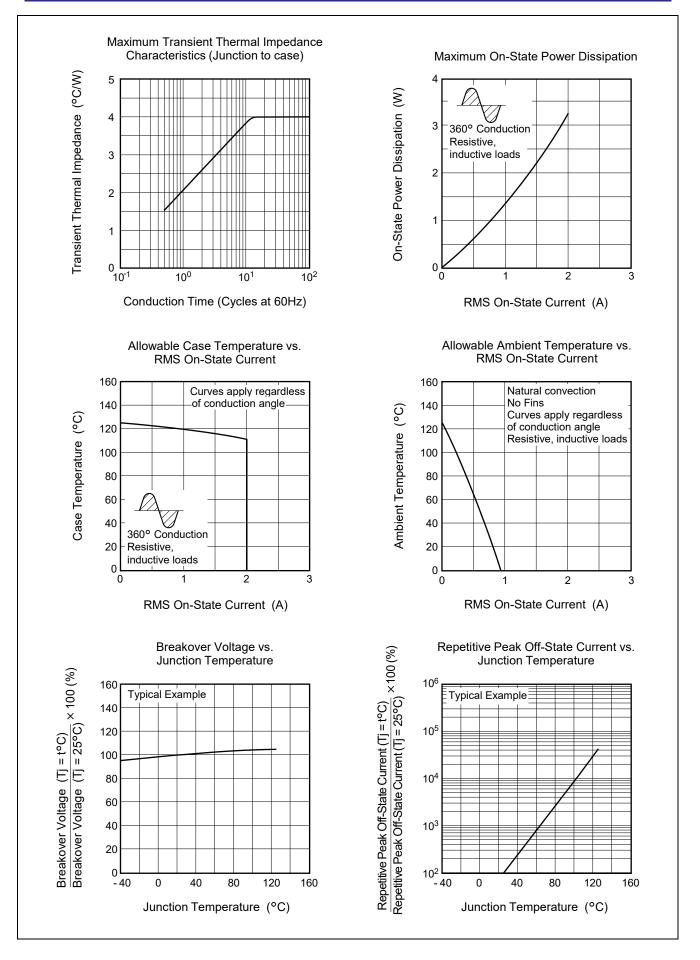
4. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below.

Test conditions	Commutating voltage and current waveforms (inductive load)			
 Junction temperature Tj = 125°C Rate of decay of on-state commutating current (di/dt)c = - 1.0 A/ms Peak off-state voltage V_D = 400 V 	Supply Voltage Main Current Main Voltage (dv/df)c VD			

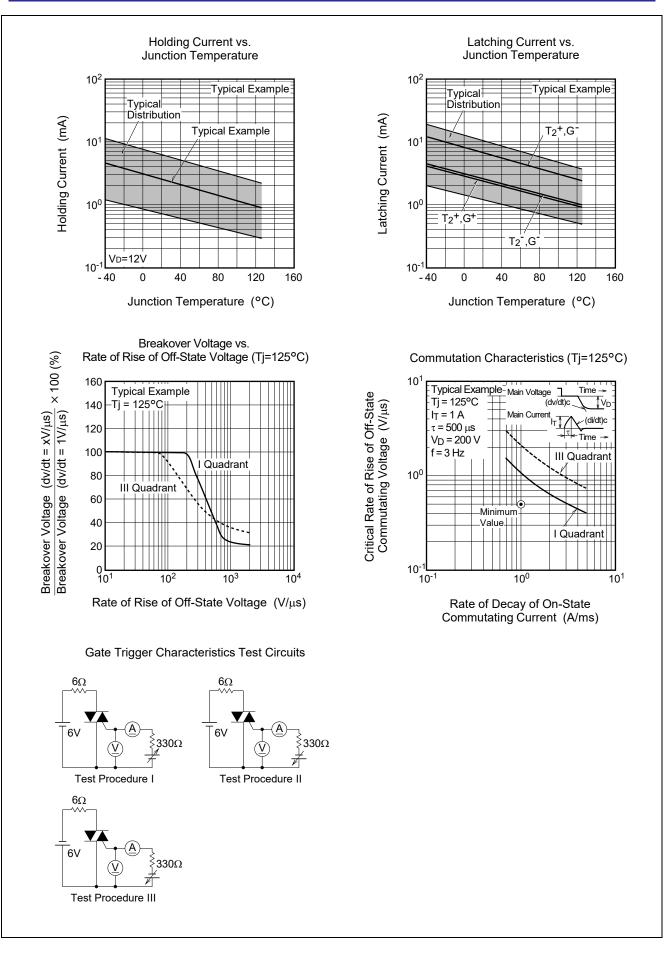
Performance Curves







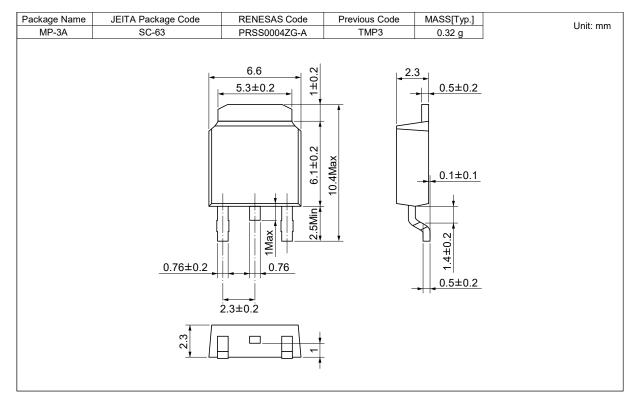
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Package Dimensions

Package Name: MP-3A



Ordering Information

Orderable Part Number	Package	Packing Note5	Quantity	Remark
BCR2AS-14A-T13#B00	MP-3A	Embossed tape	3000 pcs.	
BCR2AS-14A#B00	MP-3A	Tube	75 pcs.	Tube packing is to be abolished.

Note: 5. Please confirm the specification about the shipping in detail.

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